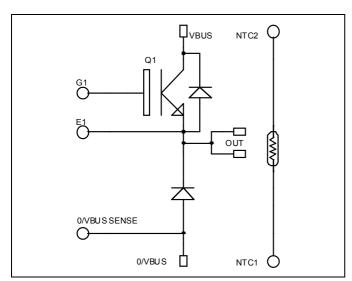


Buck chopper NPT IGBT Power Module

 $V_{CES} = 1200V$ $I_C = 150A$ @ Tc = 80°C



O/VBUS 0

SENSE D

O/VBUS

O/VBUS #

SENSE B

Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Non Punch Through (NPT) Fast IGBT
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 50 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
 - Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS compliant

Absolute maximum ratings

VBUS

Symbol	Parameter		Max ratings	Unit
V_{CES}	Collector - Emitter Breakdown Voltage		1200	V
T	Continuous Collector Current	$T_c = 25^{\circ}C$	200	
I_{C}	Continuous Conector Current	$T_c = 80^{\circ}C$	150	A
I_{CM}	Pulsed Collector Current	$T_c = 25^{\circ}C$	300	
$ m V_{GE}$	Gate – Emitter Voltage		±20	V
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	961	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	300A @ 1200V	

OUT

NTC2 #

NTC1 B

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
ī	Zero Gate Voltage Collector Current	$V_{GE} = 0V$	$T_j = 25$ °C			350	^
I_{CES}	Zero Gate Voltage Collector Current	$V_{CE} = 1200V$	$T_j = 125$ °C			600	μΑ
V	Collector Emitter saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		3.2	3.7	V
$V_{CE(sat)}$	Conector Emitter saturation voltage	$I_{\rm C} = 150 A$	$T_j = 125$ °C		3.9		v
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$, $I_C = 5 \text{ mA}$		4.5		6.5	V
I_{GES}	Gate – Emitter Leakage Current	$V_{GE} = \pm 20V, V_{CE} = 0V$				±500	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
Cies	Input Capacitance	$\begin{aligned} V_{GE} &= 0V \\ V_{CE} &= 25V \\ f &= 1MHz \end{aligned}$			10.2		
C_{oes}	Output Capacitance				1.4		nF
C_{res}	Reverse Transfer Capacitance				0.75		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C)			120		
T_{r}	Rise Time	$V_{GE} = 15V$			50		200
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm C} = 150 A$	$V_{Bus} = 600V$		310		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$		20			
$T_{d(on)}$	Turn-on Delay Time	Inductive Swite	ching (125°C)		130		
$T_{\rm r}$	Rise Time	$V_{GE} = 15V$ $V_{Bus} = 600V$ $I_{C} = 150A$			60		
$T_{d(off)}$	Turn-off Delay Time				360		ns
T_{f}	Fall Time	$R_G = 5.6\Omega$			30		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 600V$	$T_j = 125$ °C		18		ma I
E_{off}	Turn-off Switching Energy	$I_C = 150A$ $R_G = 5.6\Omega$	$T_j = 125$ °C		8		mJ

Chopper diode ratings and characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =1200V	$T_j = 25$ °C			350	^
		V _R −1200 V	$T_j = 125$ °C			600	μΑ
I_{F}	DC Forward Current		$Tc = 70^{\circ}C$		200		A
	Diode Forward Voltage	$I_F = 200A$			2	2.5	
V_{F}		$I_F = 400A$			2.3		V
		$I_F = 200A$	$T_{j} = 125^{\circ}C$		1.8		
t _{rr}	Reverse Recovery Time	$I_F = 200A$ $V_R = 800V$	$T_j = 25$ °C		420		
			$T_j = 125$ °C		520		ns
Qrr	Reverse Recovery Charge	$di/dt = 400A/\mu s \qquad T_j = 25^{\circ}C$	$T_j = 25$ °C		2.5		μС
			$T_{j} = 125^{\circ}C$		10.7		μС



 $Temperature\ sensor\ NTC\ (see\ application\ note\ APT0406\ on\ www.microsemi.com\ for\ more\ information).$

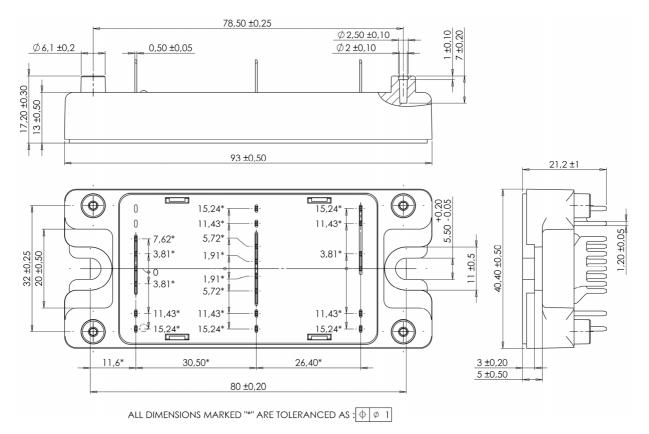
Symbol	Characteristic	Min	Typ	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_{T} = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		IGBT			0.13	°C/W
MthJC			Diode			0.32	C/ W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature -40 1				100		
Torque	Mounting torque	To heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

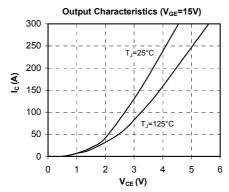
SP4 Package outline (dimensions in mm)

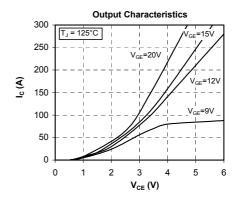


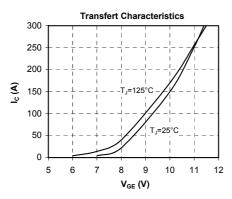
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

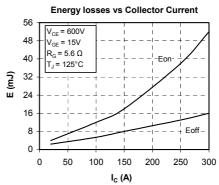


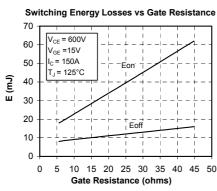
Typical Performance Curve

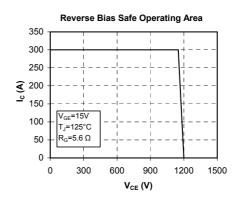


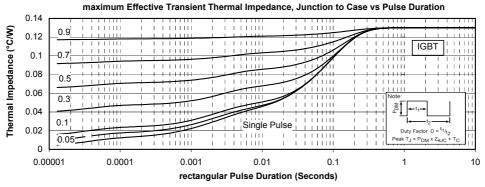




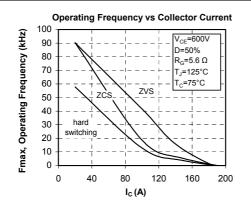


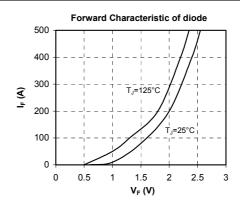


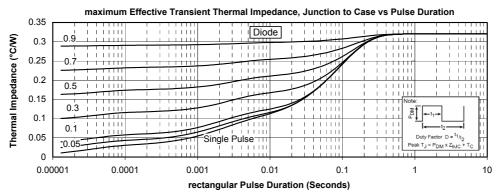












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